. reescale Semiconductor Technical Data

Document Number: MHW8342N

Rev. 3, 5/2006

√RoHS

CATV Amplifier Module

Features

- · Specified for up to 132-Channel Loading
- Excellent Distortion Performance
- Superior Gain, Return Loss and DC Current Stability over Temperature
- Silicon Bipolar Transistor Technology
- Unconditionally Stable Under All Load Conditions

Applications

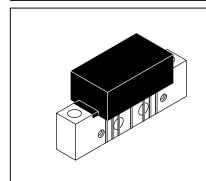
- CATV Systems Operating in the 40 to 870 MHz Frequency Range
- Single Module High Gain Line Amplifier in Cable TV Distribution System

Description

- 24 Vdc Supply, 40 to 870 MHz, CATV High Gain Forward Amplifier Module
- Replaced MHW8342. There are no form, fit or function changes with this part replacement.
- RoHS Compliant

MHW8342N

870 MHz 35.5 dB GAIN 132-CHANNEL CATV AMPLIFIER MODULE



CASE 1302-01, STYLE 1

Table 1. Maximum Ratings

Rating	Symbol	Value	Unit	
RF Voltage Input (Single Tone)	V _{in}	+55	dBmV	
DC Supply Voltage	V _{CC}	+28	Vdc	
Operating Case Temperature Range	T _C	- 20 to +100	°C	
Storage Temperature Range	T _{stg}	- 40 to +100	°C	

Table 2. Electrical Characteristics (V_{CC} = 24 Vdc, T_{C} = +30°C, 75 Ω system unless otherwise noted)

Characterist	tic	Symbol	Min	Тур	Max	Unit
Frequency Range		BW	40	_	870	MHz
Power Gain	50 MHz 870 MHz	G _p	33.2 34	34 35.5	34.8 37	dB
Slope	40 - 870 MHz	S	0.5	1.5	2.75	dB
Gain Flatness (Peak To Valley)		G _F	_	0.3	0.8	dB
Return Loss — Input (Z ₀ = 75 Ohms)	40-80 MHz 80-320 MHz 320-640 MHz 640-870 MHz	IRL	22 18 16 14	28 25 22 19	_ _ _ _	dB
Return Loss — Output (Z _o = 75 Ohms)	40-80 MHz 80-240 MHz 240-640 MHz 640-870 MHz	ORL	22 19 17 15	28 25 22 22	_ _ _ _	dB



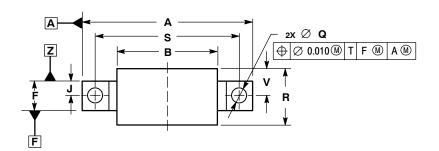
Table 2. Electrical Characteristics (V_{CC} = 24 Vdc, T_{C} = +30°C, 75 Ω system unless otherwise noted) (continued)

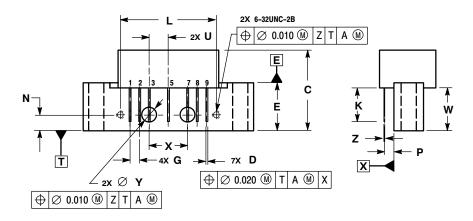
Characteristic	Symbol	Min	Тур	Max	Unit	
Composite Second Order						dBc
(V _{out} = +44 dBmV/ch., Worst Case)	79-Channel FLAT	CSO ₇₉	_	- 65	- 60	
(V _{out} = +44 dBmV/ch., Worst Case)	112-Channel FLAT	CSO ₁₁₂	_	- 55	- 50	
(V _{out} = +44 dBmV/ch., Worst Case)	132-Channel FLAT	CSO ₁₃₂	_	- 48	- 44	
Cross Modulation Distortion						dBc
$(V_{out} = +44 \text{ dBmV}, FM = 55.25 \text{ MHz})$	79-Channel FLAT	XMD ₇₉		- 63	- 60	
$(V_{out} = +44 \text{ dBmV}, FM = 55.25 \text{ MHz})$	112-Channel FLAT	XMD ₁₁₂	_	- 56	-52	
$(V_{out} = +44 \text{ dBmV}, FM = 55.25 \text{ MHz})$	132-Channel FLAT	XMD ₁₃₂	_	-56	-50	
Composite Triple Beat						dBc
(V _{out} = +44 dBmV/ch., Worst Case)	79-Channel FLAT	CTB ₇₉		- 64	- 62	
(V _{out} = +44 dBmV/ch., Worst Case)	112-Channel FLAT	CTB ₁₁₂	_	- 54	- 51	
(V _{out} = +44 dBmV/ch., Worst Case)	132-Channel FLAT	CTB ₁₃₂	_	-50	- 46	
Noise Figure	50 MHz	NF	_	3.5	4.5	dB
	550 MHz		_	4.5	_	
	870 MHz		_	5.5	6.5	
DC Current		I _{DC}	310	325	350	mA



ARCHIVE INFORMATION

PACKAGE DIMENSIONS





CASE 1302-01 ISSUE E

- NOTES:
 1. DIMENSIONS ARE IN INCHES.
 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α		1.775		45.085	
В		1.085		27.559	
C		0.840		21.336	
D	0.015	0.021	0.381	0.533	
E	0.465	0.510	11.811	12.954	
F	0.300	0.325	7.62	8.255	
G	0.100	0.100 BSC		BSC	
J	0.156	0.156 BSC		BSC	
K	0.315	0.355	8.001	9.017	
L	1.000 BSC		25.400 BSC		
N	0.165 BSC		4.191 BSC		
P	0.100	BSC	2.540	540 BSC	
Q	0.148	0.168	3.759	4.267	
R		0.600		15.24	
S	1.500	1.500 BSC		0 BSC	
U	0.200	BSC	5.080 BSC		
٧		0.250		6.350	
W	0.435		11.049		
Х	0.400	BSC	10.160 BSC		
Υ	0.152	0.163	3.861	4.140	
Z	0.009	0.011	0.229	0.279	

- STYLE 1:
 PIN 1. RF INPUT
 2. GROUND
 3. GROUND
 4. DELETED
 5. VDC
 6. DELETED
 7. GROUND
 8. GROUND
 9. RF OUTPUT



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